



DMN6013LFGQ

PowerDI3333-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C			
001/	13mΩ @ V <sub>GS</sub> = 10V	10.3A			
60V	$18m\Omega @ V_{GS} = 4.5V$	8.8A			

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor Control
- DC to DC Converters
- **Reverse Polarity Protection**

# Features and Benefits

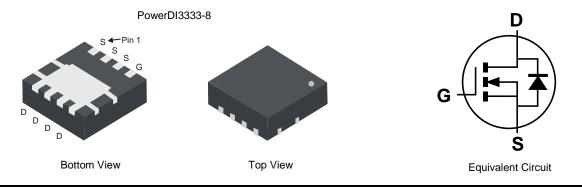
- Low R<sub>DS(ON)</sub> Ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products

60V N-CHANNEL ENHANCEMENT MODE MOSFET

- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: PowerDl<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.072 grams (Approximate)



#### Ordering Information (Note 5)

	Part Number	Case	Packaging		
	DMN6013LFGQ-7	PowerDI3333-8	2,000/Tape & Reel		
DMN6013LFGQ-13 PowerDI3333-8 3,000/Tape & Reel					
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

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2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



N63 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value 60	Unit V	
Drain-Source Voltage	V <sub>DSS</sub>			
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	۱ <sub>D</sub>	10.3 8.3	А
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	ID	45 28	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	58.3	А
Maximum Continuous Body Diode Forward Current (Note 7)		Is	3	А
Avalanche Current, L = 0.1mH	I <sub>AS</sub>	33.3	А	
Avalanche Energy, L = 0.1mH		E <sub>AS</sub>	56.8	mJ

#### **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)		PD	1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	P	123	°C/W
memar Resistance, surction to Ambient (Note 0)	t < 10s	$R_{ heta JA}$	69	
Total Power Dissipation (Note 7)		PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	P	60	°C/W
memar Resistance, sunction to Ambient (Note 7)	t < 10s	$R_{ heta JA}$	34	
Total Power Dissipation (Note 7)		PD	40	W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	3.2	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

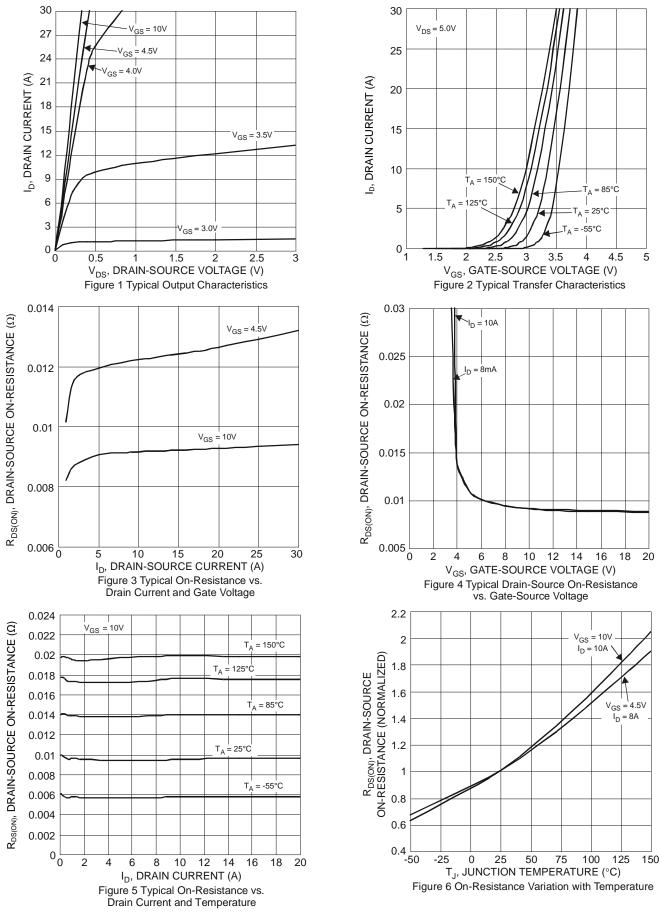
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)					1		
Drain-Source Breakdown Voltage		60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current, TJ = +25°C	IDSS		—	1	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)			•	•	•		
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	1.8	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance			9.3	13	mΩ	$V_{GS} = 10V, I_D = 10A$	
	R <sub>DS(ON)</sub>		12.3	18	11122	$V_{GS} = 4.5V, I_D = 8A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.7A$	
DYNAMIC CHARACTERISTICS (Note 9)			•	•	•		
Input Capacitance	C <sub>iss</sub>	_	2577	—	pF		
Output Capacitance	Coss	_	162	—	pF	− V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, − f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	132	—	pF		
Gate Resistance	Rg	_	0.9	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		26.6	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		55.4	_	nC		
Gate-Source Charge	Q <sub>gs</sub>		9.3	—	nC	$V_{DS} = 30V, I_D = 10A$	
Gate-Drain Charge	Q <sub>gd</sub>		12.6	—	nC	7	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.2	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	9.9	—	ns	$V_{GS} = 10V, V_{DS} = 30V,$ $R_G = 3\Omega, I_D = 10A$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	27.6	—	ns		
Turn-Off Fall Time	tF	_	11.7	—	ns	]	
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	9.4	—	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	18.6	—	nC	- I <sub>F</sub> = 10A, di/dt = 100A/μs	

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

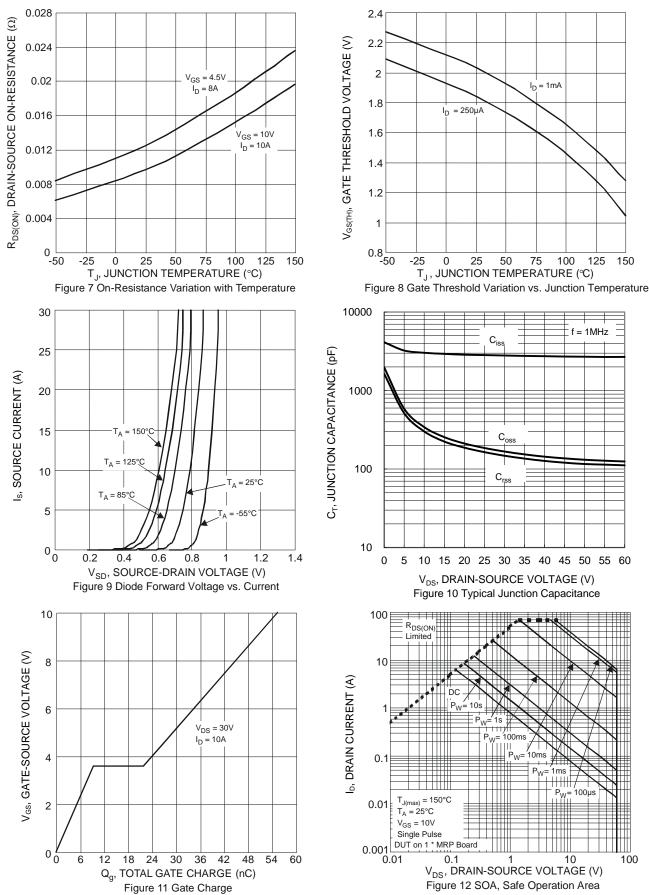


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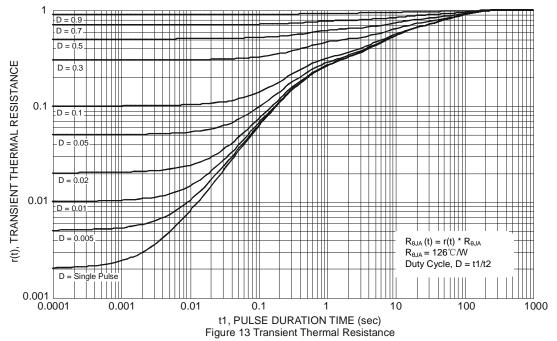




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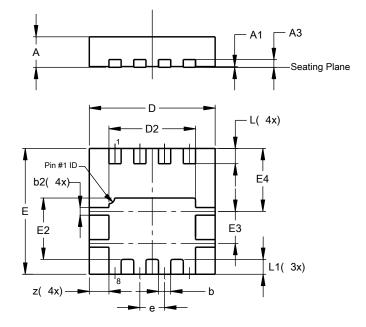




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

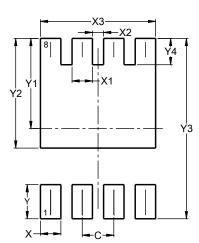
#### PowerDI3333-8



PowerDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	<b>2</b> 0.15 0.25 0.20		0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
Е	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	_	_	0.65			
L	0.35	0.45	0.40			
L1	_	_	0.39			
Z	_	_	0.515			
All I	All Dimensions in mm					

#### Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI3333-8

Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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